## **Scott Watson**

## List of Publications by Year in descending order

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|            |                | 623734       | 677142         |
|------------|----------------|--------------|----------------|
| 52         | 2,127          | 14           | 22             |
| papers     | citations      | h-index      | g-index        |
|            |                |              |                |
|            |                |              |                |
| <b>5</b> 0 | 50             | F.0          | 1000           |
| 53         | 53             | 53           | 1899           |
| all docs   | docs citations | times ranked | citing authors |
|            |                |              |                |

| #  | Article  | IF         | CITATIONS |
|----|--|------------|-----------|
| 1  | A 3-Gb/s Single-LED OFDM-Based Wireless VLC Link Using a Gallium Nitride \$mu{m LED}\$. IEEE Photonics Technology Letters, 2014, 26, 637-640.                      | 2.5        | 722       |
| 2  | High Bandwidth GaN-Based Micro-LEDs for Multi-Gb/s Visible Light Communications. IEEE Photonics Technology Letters, 2016, 28, 2023-2026.                           | 2.5        | 276       |
| 3  | Towards 10  Gb/s orthogonal frequency division multiplexing-based visible light communication using a GaN violet micro-LED. Photonics Research, 2017, 5, A35.      | 7.0        | 275       |
| 4  | 1.5 Gbit/s Multi-Channel Visible Light Communications Using CMOS-Controlled GaN-Based LEDs. Journal of Lightwave Technology, 2013, 31, 1211-1216.                  | 4.6        | 163       |
| 5  | Active-Matrix GaN Micro Light-Emitting Diode Display With Unprecedented Brightness. IEEE Transactions on Electron Devices, 2015, 62, 1918-1925.                    | 3.0        | 118       |
| 6  | Visible light communications using a directly modulated 422Ânm GaN laser diode. Optics Letters, 2013, 38, 3792.  | 3.3        | 110       |
| 7  | Characteristics and applications of micro-pixelated GaN-based light emitting diodes on Si substrates.<br>Journal of Applied Physics, 2014, 115, .                  | 2.5        | 92        |
| 8  | Temperature-dependent efficiency droop of blue InGaN micro-light emitting diodes. Applied Physics Letters, 2014, 105, .  | 3.3        | 50        |
| 9  | CMOS-Controlled Color-Tunable Smart Display. IEEE Photonics Journal, 2012, 4, 1639-1646.   | 2.0        | 44        |
| 10 | Hybrid GaN LED with capillary-bonded II–VI MQW color-converting membrane for visible light communications. Semiconductor Science and Technology, 2015, 30, 035012. | 2.0        | 28        |
| 11 | Continuous-wave operation of (Al,In)GaN distributed-feedback laser diodes with high-order notched gratings. Applied Physics Express, 2018, 11, 112701.             | 2.4        | 28        |
| 12 | Gb/s Visible Light Communications With Colloidal Quantum Dot Color Converters. IEEE Journal of Selected Topics in Quantum Electronics, 2017, 23, 1-10.             | 2.9        | 25        |
| 13 | AlGaInN laser diode technology for GHz high-speed visible light communication through plastic optical fiber and water. Optical Engineering, 2016, 55, 026112.      | 1.0        | 19        |
| 14 | Sub-megahertz linewidth 780.24  nm distributed feedback laser for <sup>87</sup> Rb applications. Opt Letters, 2020, 45, 3529.                                      | ics<br>3.3 | 18        |
| 15 | Resonant tunneling diode photodetectors for optical communications. Microwave and Optical Technology Letters, 2019, 61, 1121-1125.                                 | 1.4        | 14        |
| 16 | Optical direct intensity modulation of a 79GHz resonant tunneling diode-photodetector oscillator. Optics Express, 2019, 27, 16791.                                 | 3.4        | 13        |
| 17 | Distributed feedback InGaN/GaN laser diodes. , 2018, , .   |            | 12        |
| 18 | AlGaInN laser diode technology for defence, security and sensing applications. , 2014, , .   |            | 11        |

| #  | Article   | IF  | Citations |
|----|---|-----|-----------|
| 19 | Assessment of laser tracking and data transfer for underwater optical communications. , 2014, , .   |     | 11        |
| 20 | GaN Laser Diode Technology for Visible-Light Communications. Electronics (Switzerland), 2022, 11, 1430.   | 3.1 | 11        |
| 21 | Laser based underwater communication systems. , 2016, , .   |     | 10        |
| 22 | Directly color-tunable smart display based on a CMOS-controlled micro-LED array. , 2012, , .  |     | 9         |
| 23 | 15 Gb/s OFDM-based VLC using direct modulation of 450 GaN laser diode. , 2017, , .  |     | 8         |
| 24 | Hybrid organic/GaN photonic crystal light-emitting diode. Applied Physics Letters, 2012, 101, 141122.   | 3.3 | 6         |
| 25 | Gb/s single-LED OFDM-based VLC using violet and UV Gallium nitride & amp; #x03BC; LEDs., 2015, , .  |     | 6         |
| 26 | Single-chip discrete multitone generation. , 2015, , .  |     | 6         |
| 27 | Dynamic performance of detuned ridge waveguide AllnGaAs distributed feedback laser diodes.<br>Microwave and Optical Technology Letters, 2017, 59, 1468-1470.    | 1.4 | 5         |
| 28 | Pump-power-dependence of a CsPbBr <sub>3</sub> -in-Cs <sub>4</sub> PbBr <sub>6</sub> quantum dot color converter. Optical Materials Express, 2019, 9, 3504.     | 3.0 | 5         |
| 29 | Recent progress in distributed feedback InGaN/GaN laser diodes. , 2019, , .   |     | 5         |
| 30 | Dynamic Device Characteristics and Linewidth Measurement of InGaN/GaN Laser Diodes. IEEE Photonics Journal, 2021, 13, 1-10.                                     | 2.0 | 4         |
| 31 | Multi-gigabit data transmission using a directly modulated GaN laser diode for visible light communication through plastic optical fiber and water. , 2015, , . |     | 3         |
| 32 | InGaN/GaN Laser Diodes and their Applications. , 2018, , .  |     | 3         |
| 33 | Resonant tunneling diode oscillators for optical communications. , 2017, , .  |     | 3         |
| 34 | EML Based on Identical Epitaxial Layer, Side-Wall Grating and HSQ Planarization. IEEE Photonics Technology Letters, 2022, 34, 317-320.                          | 2.5 | 3         |
| 35 | High-bandwidth parallel data transmission using GaN/CMOS micro-LED arrays. , 2012, , .  |     | 2         |
| 36 | Advances in single mode and high power AlGaInN laser diode technology for systems applications. , 2015, , .   |     | 2         |

| #  | Article   | IF  | Citations |
|----|---|-----|-----------|
| 37 | GaN-based distributed feedback laser diodes for optical communications., 2019,,.  |     | 2         |
| 38 | High frequency modulation of a 422 nm GaN laser diode. , 2013, , .  |     | 1         |
| 39 | Applications of Single Frequency Blue Lasers. , 2019, , .   |     | 1         |
| 40 | Single Frequency Blue Lasers. , 2019, , .   |     | 1         |
| 41 | Distributed Feedback Lasers for Quantum Cooling Applications. , 2020, , .   |     | 1         |
| 42 | GaN laser diodes for quantum sensing, optical atomic clocks, and precision metrology. , 2022, , .   |     | 1         |
| 43 | Electrically tuneable spectral responsivity in gated silicon photodiodes. Applied Physics Letters, 2011, 99, .  | 3.3 | O         |
| 44 | High speed GaN micro-light-emitting diode arrays for data communications. Proceedings of SPIE, 2012, ,  | 0.8 | O         |
| 45 | Characteristics and applications of InGaN micro-light emitting diodes on Si substrates. , 2013, , .   |     | 0         |
| 46 | AlGaInN laser diode technology and systems for defence and security applications. , 2015, , .   |     | 0         |
| 47 | AlGalnN laser diode technology and systems for defence and security applications. Proceedings of SPIE, 2015, , .  | 0.8 | O         |
| 48 | Optical Characteristics Analysis of Resonant Tunneling Diode Photodiode Based Oscillators. , 2018, , .  |     | 0         |
| 49 | The effect of detuned wavelength in the dynamic performance of distributed feedback lasers operating at O band and C band. Microwave and Optical Technology Letters, 2020, 62, 1466-1470. | 1.4 | O         |
| 50 | Electroabsorption Modulated Laser Based on Identical Epitaxial Layer and Transmission Line Technology. , 2021, , .  |     | 0         |
| 51 | Ge-on-Si Single-Photon Avalanche Diode Detectors with Low Noise Equivalent Power in the Short-Wave Infrared., 2021,,.   |     | 0         |
| 52 | GaN laser diodes for quantum sensing. , 2020, , .   |     | 0         |